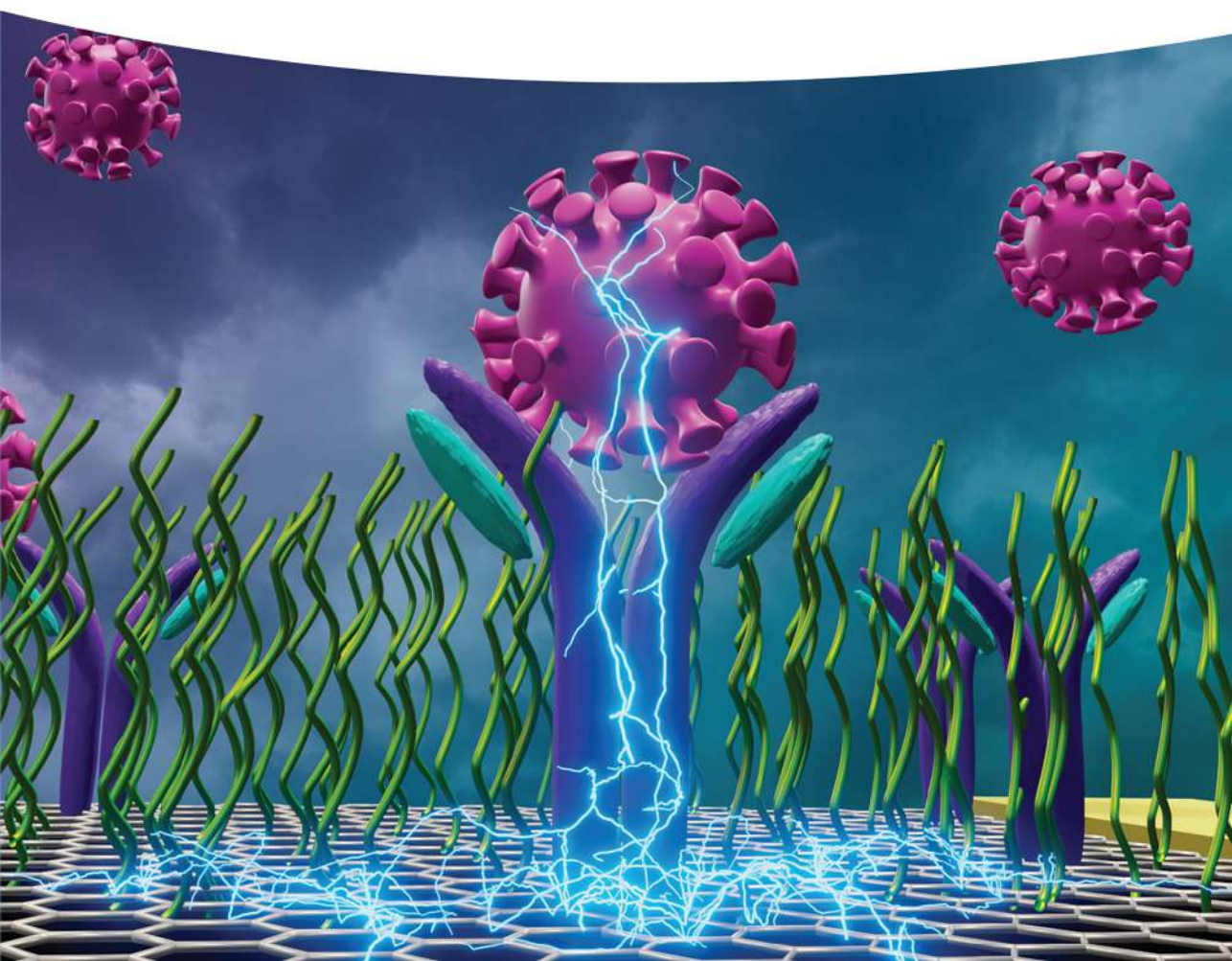


Edited by Omar Azzaroni and Wolfgang Knoll

Graphene Field-Effect Transistors

Advanced Bioelectronic Devices for Sensing Applications



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WILEY-VCH

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Cover Image: Surface engineering of graphene-based FET biosensors for virus detection. Credit: Gonzalo E. Fenoy & M. Lorena Cortez

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This book is dedicated to Elias Drake, Ivo, and Dante.

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Foreword

Sensors are ubiquitous in modern life. They surround us, monitor our body function and our environment, protect us, help us communicate with each other, and make work more efficient and less strenuous. It is not at all surprising that the market demand for better and more efficient sensors is only increasing. For instance, in 2019, the sensor market size was of approximately US\$ 167 billion, and it is expected to reach US\$ 346 billion by 2028. However, progress in sensor's development passes unequivocally through the evolution of advanced materials that can convert different types of environmental energy into energy that can be processed either digitally or analogically with high accuracy, short response time, long-term thermal and noise stability, linearity, low power consumption, and cost. These characteristics impose stringent constraints on the type of materials that can be used in sensor development. Since its isolation in 2004, graphene has been lauded as the ultimate material for sensing applications because of its unique physical properties, namely, high electrical and thermal conductivity, large Young modulus, high sensitivity to chemicals and strain, and, most of all, its large surface area to volume ratio. It is famously said that the interface is the device. We can also say that *the surface is the sensor*. Detection usually occurs at the surface of a material and, hence, the larger the ratio of surface area to the volume of the device, the higher the ability of the device to detect. Graphene sensors have high accuracy because graphene is a pure surface (no bulk) and can detect minute amounts of chemical, electrical, magnetic, and stress signals and convert them into signals that can be processed and communicated to other devices. The literature on graphene sensors has grown exponentially in the last decade, and it is quite hard to follow this growth and even separate "tares from wheat." The book by Omar Azzaroni and Wolfgang Knoll on advanced bioelectronic devices for sensing applications using graphene field-effect transistors

is a breath of fresh air in this crowded research space. I believe it will become a fundamental reference for any researcher, engineer, or industrialist who is interested in learning why graphene is the ultimate sensor material.

Singapore, November 2022

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Preface

The discovery of a layer of graphene, one atom-thin, by Andre Geim and Konstantin Novoselov (Nobel Prize in Physics 2010) at the University of Manchester (UK) in 2004 created a whole new scientific field and resulted in robust technologies that strongly contributed to the development of advanced devices.

Among different graphene-based innovations, the graphene field-effect transistor (GFET) represents a remarkable example of an advanced electronic device. GFETs employ the typical configuration of a field-effect transistor (FET) device using a graphene channel – constituted of a lattice of carbon atoms that is only one atom thick! – between source and drain. Keeping this in mind, we can understand why GFETs exhibit unprecedented sensitivity, which can be exploited in a wide variety of sensing and biosensing applications. Contrary to the conventional view of bulk semiconductors, such as silicon, used in traditional FETs, the use of graphene to create FETs marks a profound departure from long-established notions and approaches to create semiconductor devices and puts them into practice.

From a historical perspective, traditional transistor sensors are three-dimensional semiconductor devices in which changes in electric charge at the surface of the channel do not always translate into a device response. As the reader can probably imagine, this fact can dramatically limit the sensitivity of the device.

In stark contrast, in GFETs, the channel is made from a two-dimensional material, which directly exposes the channel to any molecules in the surroundings. In this scenario, the local gating effect is much more effective than that in conventional devices because the species modulating the electric field can be directly attached to the “entire” transistor channel.

While the use of GFETs in biosensing and bioelectronics has been in the experimental phase for years, it is only recently that this technology has gradually shifted to a commercial stage [1–3]. For instance, a report from McKinsey estimates that graphene-related technologies will become a US\$ 70B market by 2030 [4].

By nature, the subject of bioelectronics is diverse and interdisciplinary, and, as such, chemists, biologists, physicists, materials scientists, and engineers can make valuable contributions to the field. It is now clear within the scientific community that the successful translation of research in graphene transistors to commercial

reality requires the harmonization of four universes: electronics, biology, physics, and chemistry. Indeed, the journey from basic science to technological applications has been compellingly described by Herbert Kroemer (Nobel Prize in Physics 2000) [5]: “*Even if the process from science and technology to applications is opportunistic rather than deterministic, we can speed up this process by better cross-discipline communication between scientists, technologists, and application engineers.*” In this regard, a non-negligible merit of engineers, physicists, biologists, and chemists has been their willingness to overcome the fences in which they have been traditionally confined and to promote collaboration with “apparently” unrelated research areas.

In this book, our aim is to show the wide potential of GFETs as advanced bioelectronic platforms and also to promote the potential of the technology among scientists, students, postdoctoral fellows, engineers, and industrial researchers. In addition, we also hope that this book will help convince decision-makers from academia, government, and industry to cooperate in developing a comprehensive GFET roadmap to accelerate the manufacturing and commercialization of this promising technology.

We are pleased to have edited this book, and we are honored that so many contributors from all over the world (see map below) have accepted our invitation and taken time to write significant contributions. We are grateful to the authors who have always been very responsive and enthusiastic about the idea of the book. The invaluable efforts of these authors from 14 different countries with 38 different affiliations have helped build a comprehensive book that may be used as an advanced textbook by graduate students and young scientists, as well as a valuable reference for academic and industrial professionals performing research and development in the specific area of biosensing and bioelectronics.

Last, but not least, we thank Antonio H. Castro Neto, a pioneer in the field of graphene as an electronic material, for his Foreword, and we thank you so much for taking the time to read this book.

Wolfgang Knoll
Vienna
March 2023

Omar Azzaroni
La Plata
March 2023



References

- 1 Graphenea. <https://www.graphenea.com/> (accessed 30 March 2023).
- 2 Cardea. <https://www.cardeabio.com/> (accessed 30 March 2023).
- 3 Gisens Biotech. <https://www.gisensbiotech.com/> (accessed 30 March 2023).
- 4 Batra, G., Santhanam, N., Surana, K. (2018). Graphene: the next S-curve for semiconductors? McKinsey Insights. https://www.mckinsey.com/industries/semiconductors/our-insights/graphene-the-next-s-curve-for-semiconductors?utm_campaign=1millionth-sensor&utm_source=cision&utm_medium=cision&utm_term=mckinsey&utm_content=mckinsey (accessed 30 March 2023).
- 5 Kroemer, H. (2005). *Phys. Status Solidi A* 202: 957–964.